

Appl. No. 10/714,285
Response dated Aug. 7, 2006
Reply to Office action dated Mar. 10, 2006

Amendments to the Drawings:

The attached sheet of drawings includes changes to Figs 1A, 1B, and 2. These sheets, which include Figs. 1A, 1B, 2, and 3, replace the original sheets including Figs. 1A, 1B, 2, and 3. In Figures 1A, 1B, and 2, previously omitted legends "prior art" are added.

Attachment: Replacement Sheets
 Annotated Sheets showing changes

Remarks

Applicants thank Examiner Im for the careful examination of this application and the clear explanation of the claim rejections and other objection. In response to the Office Action of March 10, 2006, applicants amend this application as follows:

Responding to the objection to claim 16, applicants change the term "n layer" to "nth layer" in claim 16 and through out this application. No new matter is added.

Regarding claims 1 and 16, applicants amend the claims by adding claim limitation so that in the package of claim 1 and in the device of claim 16 the top metal layer is free of signal traces. This limitation is fully supported in the original specification and the original drawings; and is not disclosed in the Cohn patent.

Applicants amend claim 18 to describe the invention more clearly.

Applicants also add 2 new claims – claims 23 and 24, which add limits to claims 6 and 19 so that the two dielectric layers are of similar dielectric constant. This is fully supported in the original specification and is not disclosed in the Cohn patent.

Drawing figures 1A, 1B, and 2 are amended to add the previously omitted legends "prior art."

Applicants respectfully request further examination of this application and timely allowance of all pending claims.

Respectfully submitted,
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